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Team Nexperia

60 V, 1 A NPN medium power transistors Rev. 8 — 24 October 2011

#### 1. **Product profile**

### 1.1 General description

NPN medium power transistor series in Surface-Mounted Device (SMD) plastic packages.

#### **Product overview** Table 1.

Type number <sup>[1]</sup>	Package		PNP complement	
	NXP	JEITA	JEDEC	
BCP55	SOT223	SC-73	-	BCP52
BCX55	SOT89	SC-62	TO-243	BCX52
BC55PA	SOT1061	-	-	BC52PA

[1] Valid for all available selection groups.

### 1.2 Features and benefits

- High current
- Three current gain selections
- High power dissipation capability
- Exposed heatsink for excellent thermal and electrical conductivity (SOT89, SOT1061)
- Leadless very small SMD plastic package with medium power capability (SOT1061)
- AEC-Q101 gualified

### 1.3 Applications

- Linear voltage regulators
- Low-side switches
- Battery-driven devices
- Power management
- MOSFET drivers
- Amplifiers

### 1.4 Quick reference data

#### Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	60	V
I <sub>C</sub>	collector current		-	-	1	А
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-	2	А
h <sub>FE</sub>	DC current gain	$V_{CE} = 2 \text{ V}; \text{ I}_{C} = 150 \text{ mA}$	<u>[1]</u> 63	-	250	
	h <sub>FE</sub> selection -10	$V_{CE} = 2 \text{ V}; \text{ I}_{C} = 150 \text{ mA}$	<u>[1]</u> 63	-	160	
	h <sub>FE</sub> selection -16	$V_{CE} = 2 \text{ V}; \text{ I}_{C} = 150 \text{ mA}$	[ <u>1]</u> 100	-	250	

[1] Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta = 0.02$ .



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### 2. Pinning information

Pin	Description	Simplified outline	Graphic symbol	
SOT223				
1	base			
2	collector		2, 4	
3	emitter		1	
4	collector $\boxed{1 \ 2 \ 3}$			
SOT89			sym016	
1	emitter		_	
2	collector		2 J	
3	base		31 sym042	
SOT1061				
1	base		_	
2	emitter	3	3	
3	collector	1   2     Transparent top view	1 - 2 sym021	

### 3. Ordering information

Table 4. Order	ring inform	ation					
Type number <sup>[1]</sup>	Package	ckage					
	Name	Description	Version				
BCP55	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223				
BCX55	SC-62	plastic surface-mounted package; exposed die pad for good heat transfer; 3 leads	SOT89				
BC55PA	HUSON3	plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body $2 \times 2 \times 0.65$ mm	SOT1061				

[1] Valid for all available selection groups.

BCP55_BCX55_BC55PA	
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### 4. Marking

Table 5.   Marking codes	
Type number	Marking code
BCP55	BCP55
BCP55-10	BCP55/10
BCP55-16	BCP55/16
BCX55	BE
BCX55-10	BG
BCX55-16	BM
BC55PA	AW
BC55-10PA	BH
BC55-16PA	BJ

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### 5. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	60	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	60	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	5	V
l <sub>C</sub>	collector current		-	1	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	2	А
I <sub>B</sub>	base current		-	0.3	А
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms	-	0.3	А
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	BCP55		<u>[1]</u> _	0.65	W
			[2] _	1.00	W
			[3]	1.35	W
	BCX55		<u>[1]</u> _	0.50	W
			[2]	0.95	W
			[3]	1.35	W
	BC55PA		<u>[1]</u> _	0.42	W
			[2]	0.83	W
			[3]	1.10	W
			[4] _	0.81	W
			<u>[5]</u>	1.65	W
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

 $\label{eq:compared} \ensuremath{\left[2\right]} \quad \mbox{Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm^2.$ 

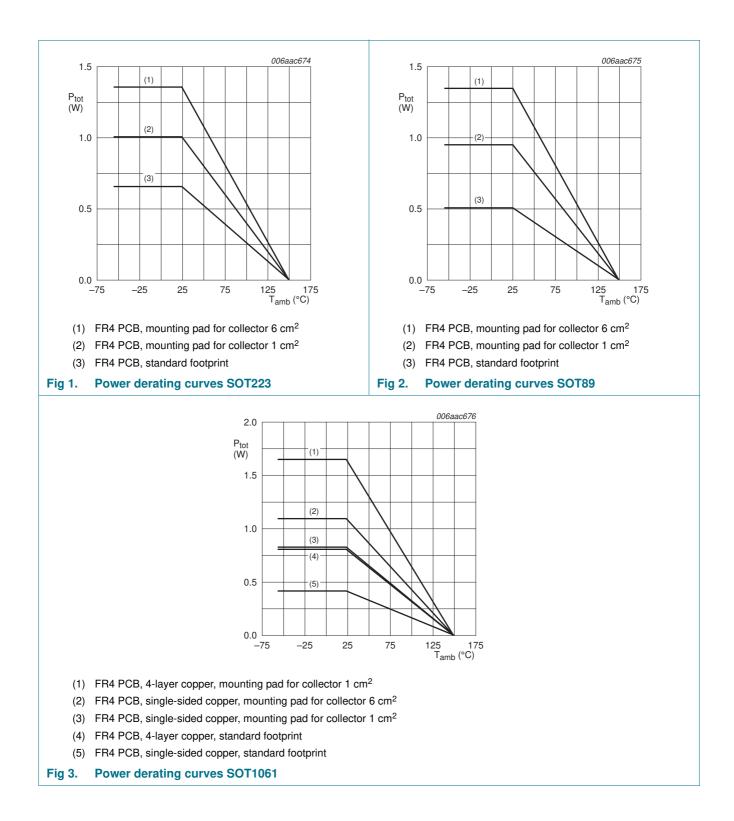
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

### BCP55; BCX55; BC55PA

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### 6. Thermal characteristics

Symbol	Parameter	Conditions	I	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air					
	BCP55		[1] -	-	-	192	K/W
			[2]	-	-	125	K/W
			[3]	-	-	93	K/W
	BCX55		[1] -	-	-	250	K/W
			[2]	-	-	132	K/W
			[3]	-	-	93	K/W
BC55F	BC55PA		[1] -	-	-	298	K/W
			[2]	-	-	151	K/W
			[3]	-	-	114	K/W
			[4]	-	-	154	K/W
			[5]	-	-	76	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point						
	BCP55		-	-	-	16	K/W
	BCX55		-	-	-	16	K/W
	BC55PA		-	-	-	20	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

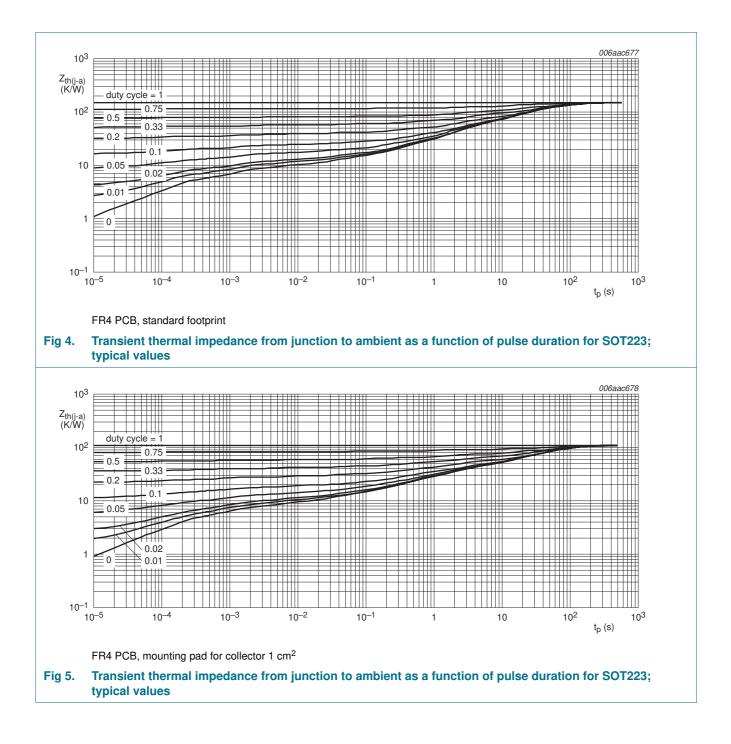
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

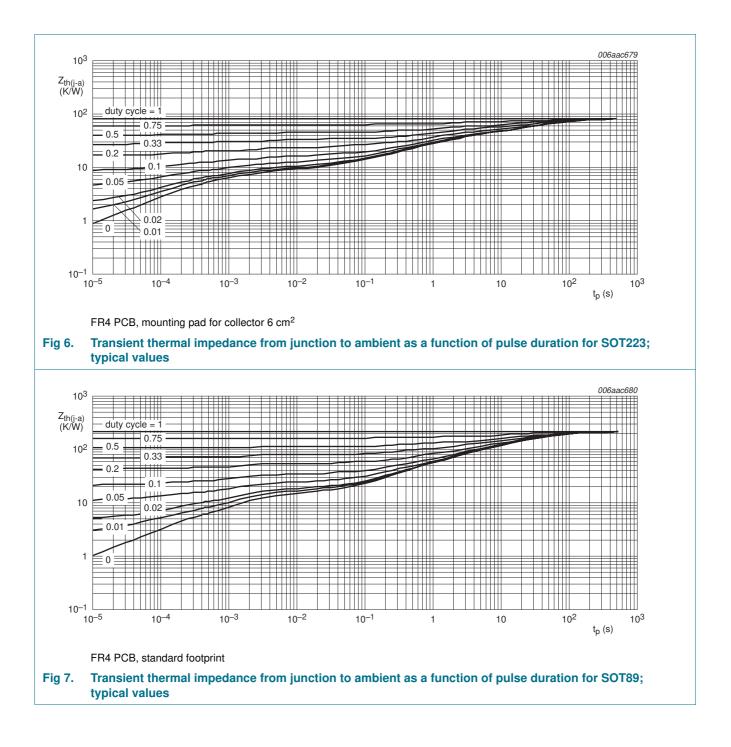
[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

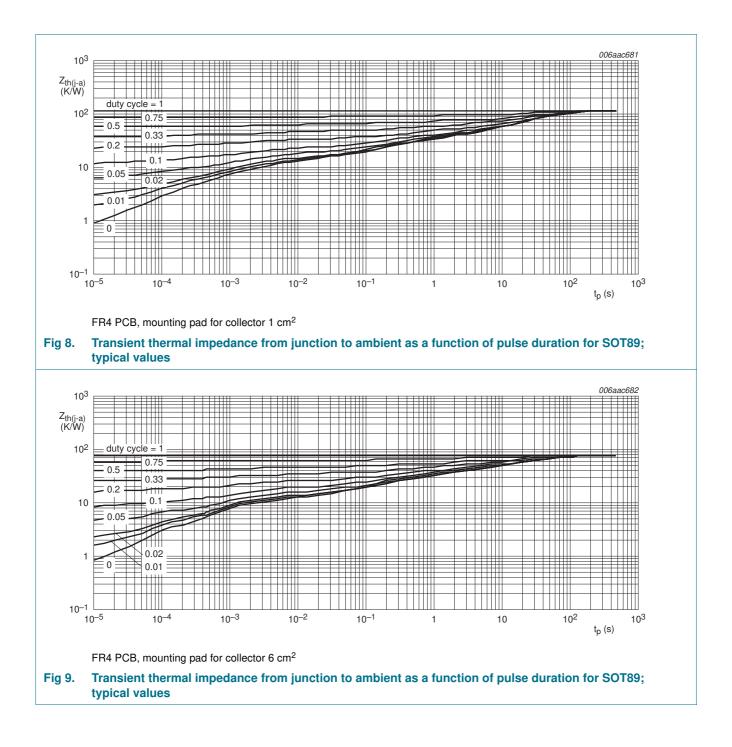
### BCP55; BCX55; BC55PA



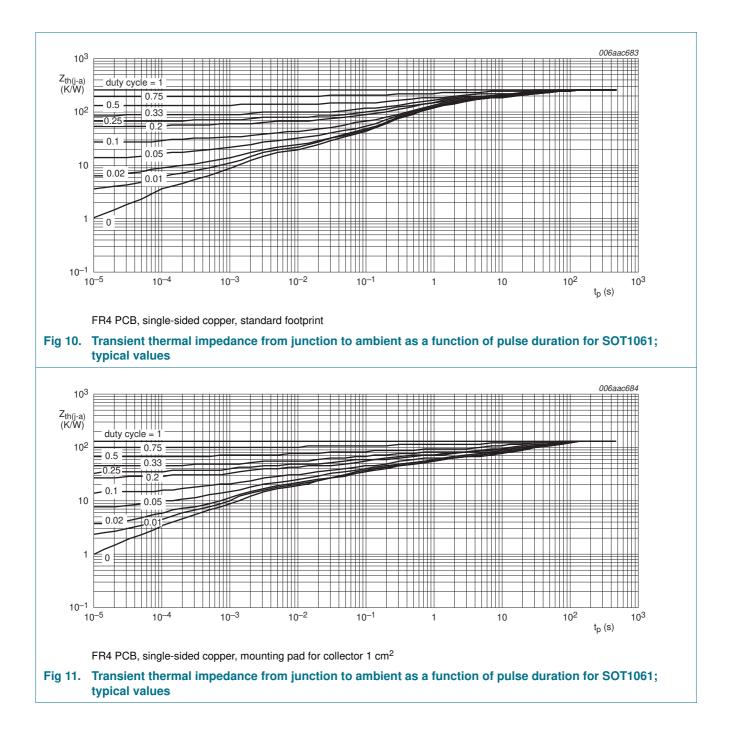
### BCP55; BCX55; BC55PA



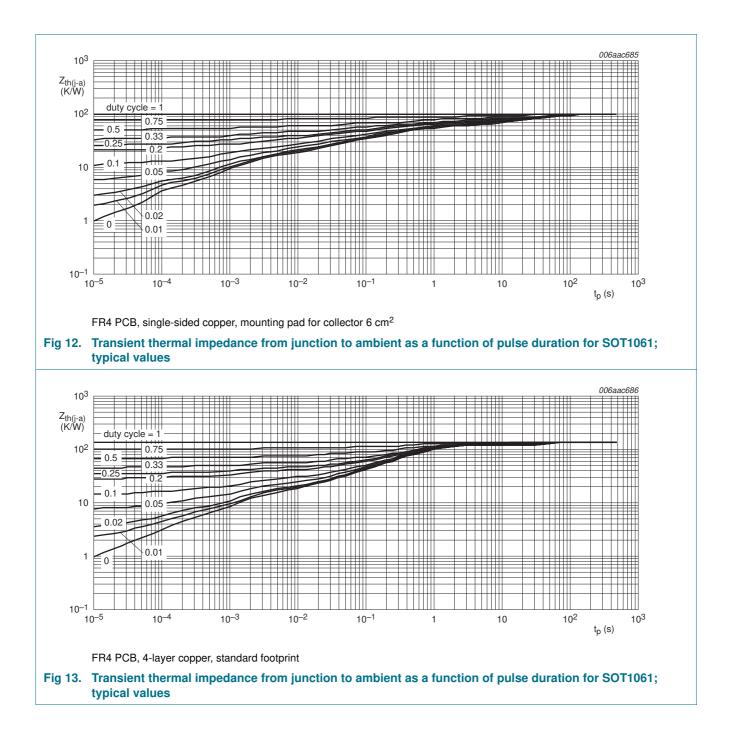
### BCP55; BCX55; BC55PA



### BCP55; BCX55; BC55PA

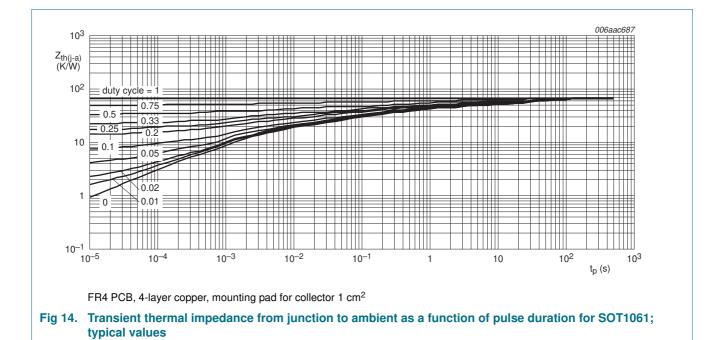


### BCP55; BCX55; BC55PA



### BCP55; BCX55; BC55PA

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### 7. Characteristics

#### Table 8.Characteristics

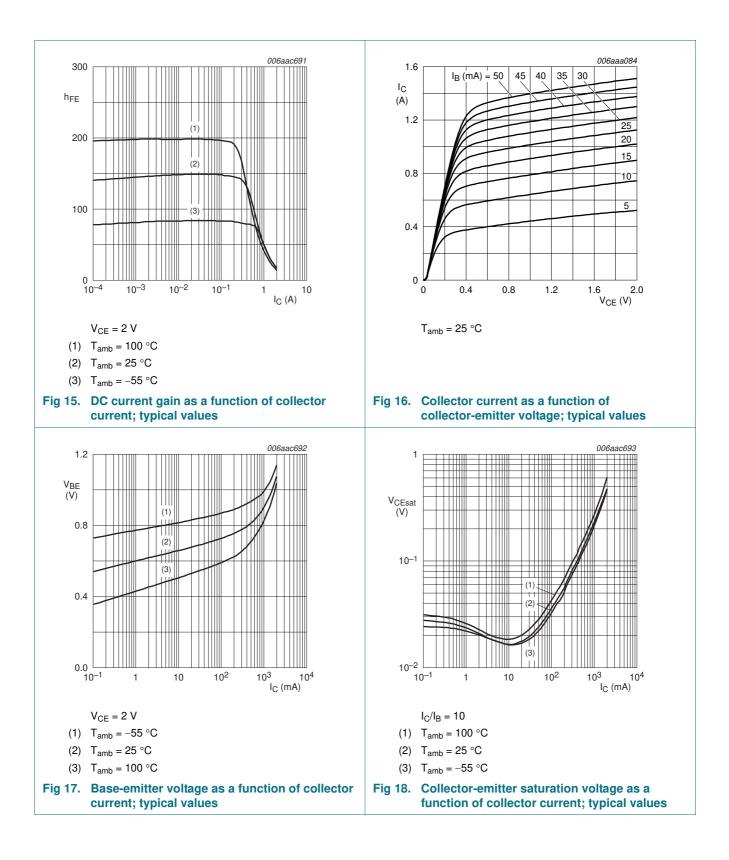
T<sub>amb</sub> = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A}$		-	-	100	nA
	current	$\label{eq:VCB} \begin{array}{l} V_{CB} = 30 \text{ V}; \text{ I}_{E} = 0 \text{ A}; \\ T_{j} = 150 \ ^{\circ}\text{C} \end{array}$		-	-	10	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$		-	-	100	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = 2 V$					
	$I_{\rm C} = 5  \rm{mA}$	[1]	63	-	-		
		I <sub>C</sub> = 150 mA	[1]	63	-	250	
		I <sub>C</sub> = 500 mA	[1]	40	-	-	
	DC current gain	V <sub>CE</sub> = 2 V					
	h <sub>FE</sub> selection -10	I <sub>C</sub> = 150 mA	[1]	63	-	160	
	h <sub>FE</sub> selection -16	I <sub>C</sub> = 150 mA	[1]	100	-	250	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{\rm C}$ = 500 mA; $I_{\rm B}$ = 50 mA	[1]	-	-	0.5	V
V <sub>BE</sub>	base-emitter voltage	$V_{CE} = 2 \text{ V}; \text{ I}_{C} = 500 \text{ mA}$	[1]	-	-	1	V
C <sub>c</sub>	collector capacitance	$\label{eq:VCB} \begin{array}{l} V_{CB} = 10 \text{ V};  \text{I}_{E} = \text{i}_{e} = 0 \text{ A}; \\ \text{f} = 1 \text{ MHz} \end{array}$		-	6	-	pF
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 50 mA; f = 100 MHz		100	180	-	MHz

[1] Pulse test:  $t_p \leq 300 \ \mu s$ ;  $\delta = 0.02$ .

### BCP55; BCX55; BC55PA

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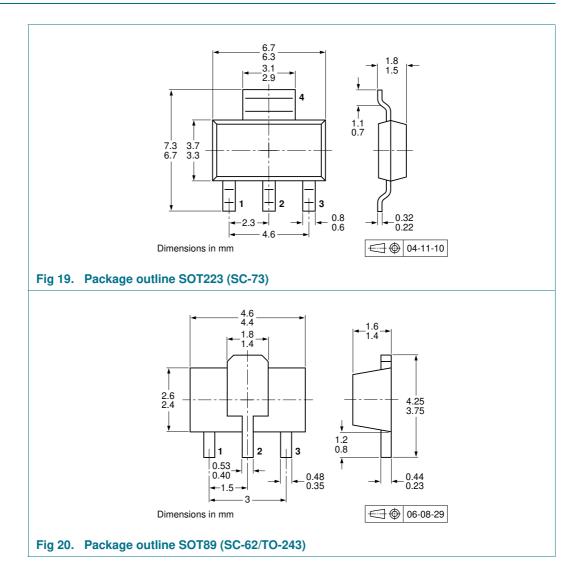
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### 8. Test information

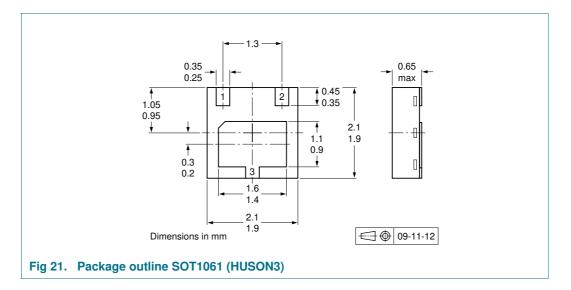
#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 9. Package outline



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### **10. Packing information**

#### Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Туре	Package	Description		Packin	g quant	ity
number <sup>[2]</sup>	humber <sup>121</sup>			1000	3000	4000
BCP55	SOT223	8 mm pitch, 12 mm tape and reel		-115	-	-135
BCX55	SOT89	8 mm pitch, 12 mm tape and reel; T1	[3]	-115	-	-135
		8 mm pitch, 12 mm tape and reel; T3	[4]	-146	-	-
BC55PA	SOT1061	4 mm pitch, 8 mm tape and reel		-	-115	-

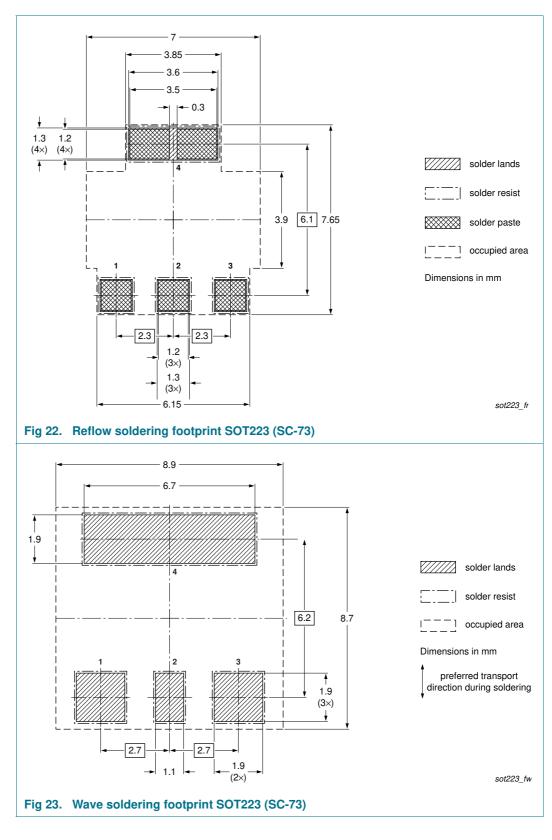
[1] For further information and the availability of packing methods, see <u>Section 14</u>.

[2] Valid for all available selection groups.

- [3] T1: normal taping
- [4] T3: 90° rotated taping

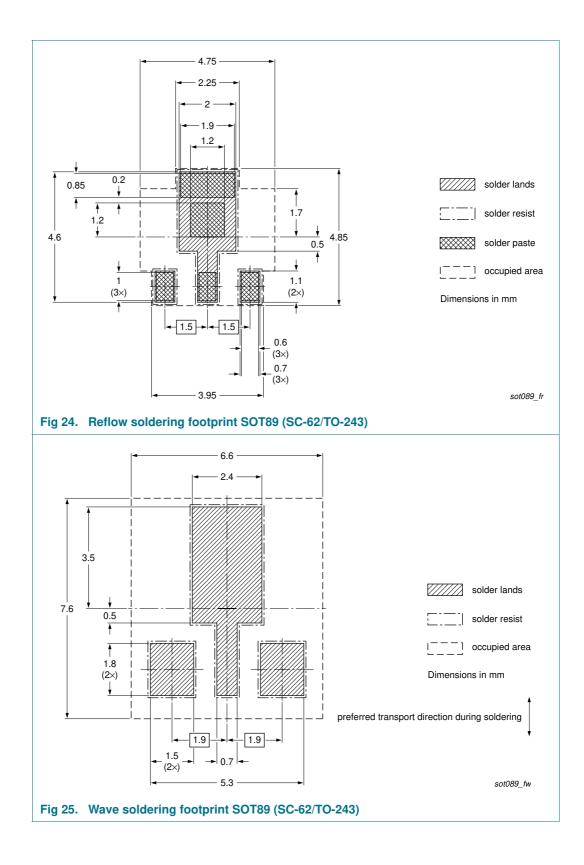
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### 11. Soldering

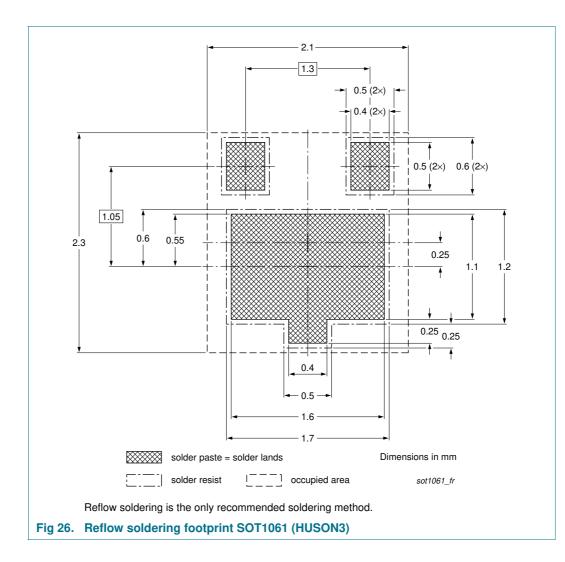


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### 12. Revision history

#### Table 10.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BCP55_BCX55_BC55PA v.8	20111024	Product data sheet	-	BC637_BCP55_BCX55 v.7		
Modifications:	<ul> <li>Type numb</li> </ul>	er removed: BC637				
	<ul> <li>Type number added: BC55PA, BC55-10PA and BC55-16PA</li> </ul>					
	<u>Section 1 "Product profile"</u> : updated					
	<u>Section 2 "Pinning information"</u> : updated					
	<ul> <li><u>Table 6</u> and <u>7</u>: updated according to latest measurements</li> </ul>					
	<ul> <li>Figure 1, 2,</li> </ul>	4, 5, 7 to 9, 15, 17 and 18	: updated			
	<ul> <li>Figure 3, 6,</li> </ul>	10 to 14: added				
	<u>Section 8 "Test information"</u> : added					
	<u>Section 10 "Packing information"</u> : updated					
	<u>Section 11 "Soldering"</u> : added					
	Section 13	"Legal information": update	ed			
BC637_BCP55_BCX55 v.7	20070625	Product data sheet	-	BC637_BCP55_BCX55 v.6		
BC637_BCP55_BCX55 v.6	20050218	Product data sheet	CPCN2004050	BC635_637_639 v.4		
			29	BCP54_55_56 v.5		
				BCX54_55_56 v.4		
BC635_637_639 v.4	20011010	Product specification	-	BC635_637_639 v.3		
BCP54_55_56 v.5	20030206	Product specification	-	BCP54_55_56 v.4		
BCX54_55_56 v.4	20011010	Product specification	-	BCX54_55_56 v.3		

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### 13. Legal information

### 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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60 V, 1 A NPN medium power transistors

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